

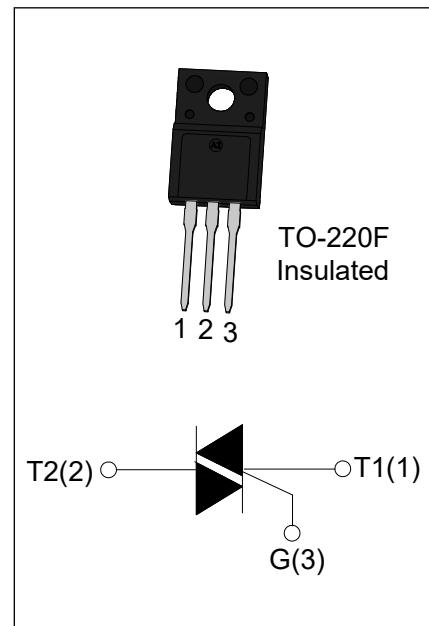


## ACJM0835-8F 8A TRIACs

Rev.1

## DESCRIPTION:

ACJM0835-8F triacs with low holding and latching current are especially recommended for use on middle and small resistance type power load. From all three terminals to external heatsink, ACJM0835-8F provides a rated insulation voltage of 2000 V<sub>RMS</sub>. (File ref: E252906). Package TO-220F is RoHS compliant. (2011/65/EU)



## MAIN FEATURES

Symbol	Value	Unit
I <sub>T(RMS)</sub>	8	A
V <sub>DRM</sub> / V <sub>RRM</sub>	800	V

## ABSOLUTE MAXIMUM RATINGS

Parameter	Symbol	Value	Unit
Storage junction temperature range	T <sub>stg</sub>	-40 - 150	°C
Operating junction temperature range	T <sub>j</sub>	-40 - 125	°C
Repetitive peak off-state voltage (T <sub>j</sub> =25°C)	V <sub>DRM</sub>	800	V
Repetitive peak reverse voltage (T <sub>j</sub> =25°C)	V <sub>RRM</sub>	800	V
RMS on-state current (T <sub>c</sub> =100°C)	I <sub>T(RMS)</sub>	8	A
Non repetitive surge peak on-state current (full cycle, F=50Hz)	I <sub>TSM</sub>	80	A
I <sup>2</sup> t value for fusing (tp=10ms)	I <sup>2</sup> t	32	A <sup>2</sup> s
Critical rate of rise of on-state current (I <sub>G</sub> =2 × I <sub>GT</sub> )	dI/dt	50	A/μs
Peak gate current	I <sub>GM</sub>	4	A
Average gate power dissipation	P <sub>G(AV)</sub>	1	W
Peak gate power	P <sub>GM</sub>	5	W
Peak pulse voltage (T <sub>j</sub> =25°C; non-repetitive,off-state;FIG.7)	V <sub>pp</sub>	3	kV

ELECTRICAL CHARACTERISTICS ( $T_j=25^\circ\text{C}$  unless otherwise specified)

Symbol	Test Condition	Quadrant		Value	Unit
$I_{GT}$	$V_D=12\text{V}$ $R_L=33\Omega$	I - II - III	MAX	35	mA
$V_{GT}$		I - II - III	MAX	1.5	V
$V_{GD}$	$V_D=V_{DRM}$ $T_j=125^\circ\text{C}$ $R_L=3.3\text{K}\Omega$	I - II - III	MIN	0.2	V
$I_L$	$I_G=1.2I_{GT}$	I - III	MAX	50	mA
		II		70	
$I_H$	$I_{TM}=100\text{mA}$		MAX	40	mA
$dv/dt$	$V_D=2/3V_{DRM}$ Gate Open $T_j=125^\circ\text{C}$		MIN	1000	V/ $\mu\text{s}$

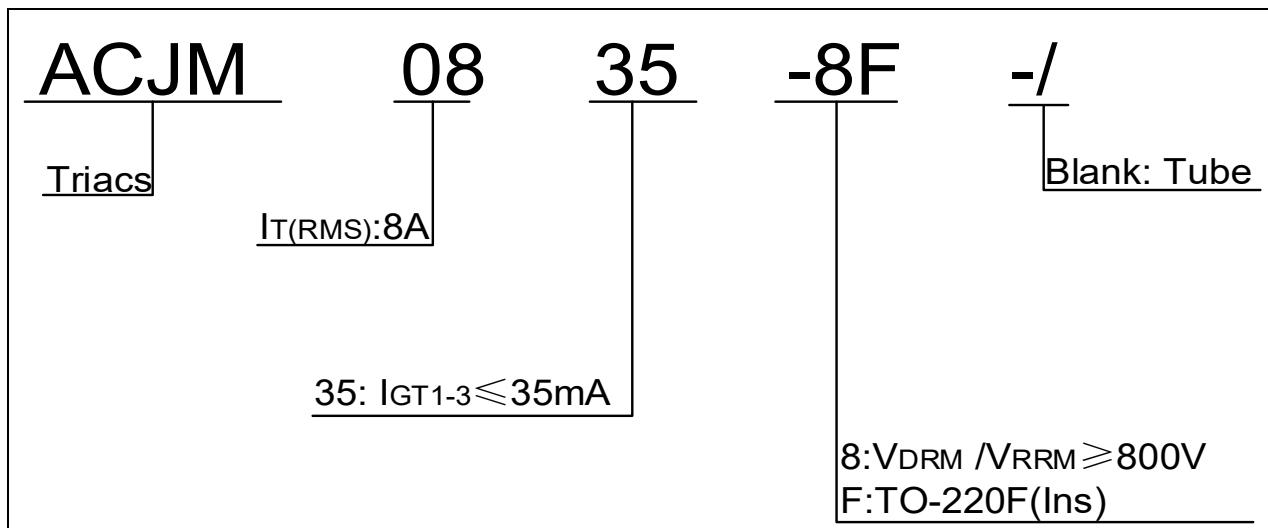
## STATIC CHARACTERISTICS

Symbol	Parameter		Value(MAX)	Unit
$V_{TM}$	$I_{TM}=11\text{A}$	$t_p=380\mu\text{s}$	1.5	V
$V_{TO}$	Threshold voltage	$T_j=125^\circ\text{C}$	0.95	V
$R_d$	Dynamic resistance	$T_j=125^\circ\text{C}$	33	$\text{m}\Omega$
$I_{DRM}$	$V_D=V_{DRM}$	$T_j=25^\circ\text{C}$	5	$\mu\text{A}$
$I_{RRM}$		$T_j=125^\circ\text{C}$	1	mA

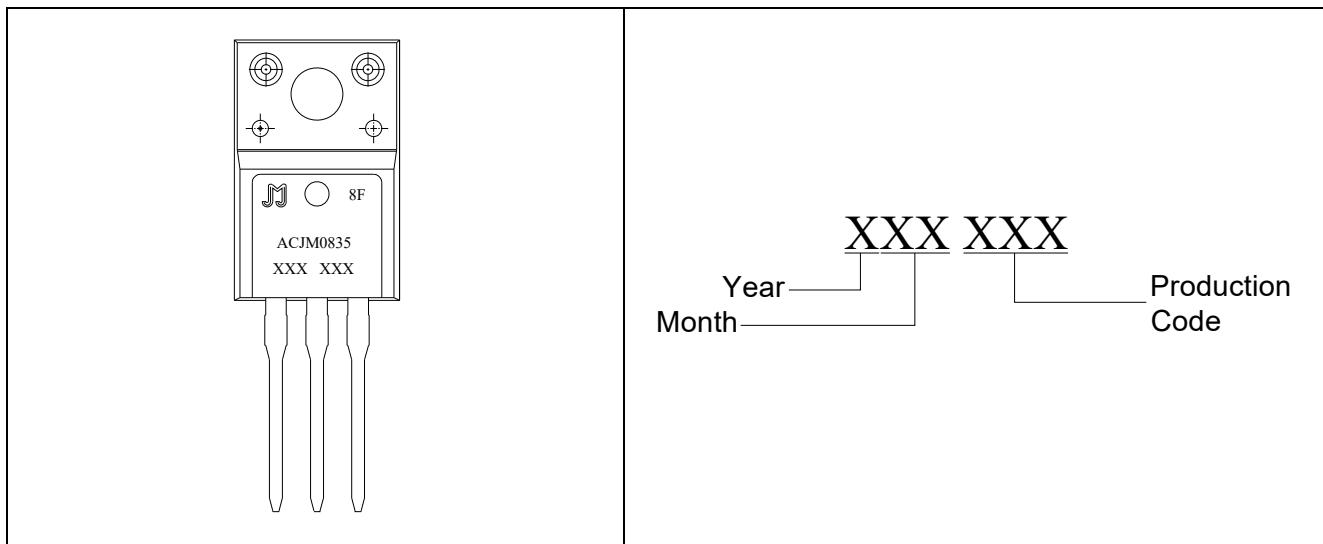
## THERMAL RESISTANCES

Symbol	Parameter		Value	Unit
$R_{th(j-c)}$	junction to case(AC)	TO-220F(Ins)	2.5	$^\circ\text{C}/\text{W}$

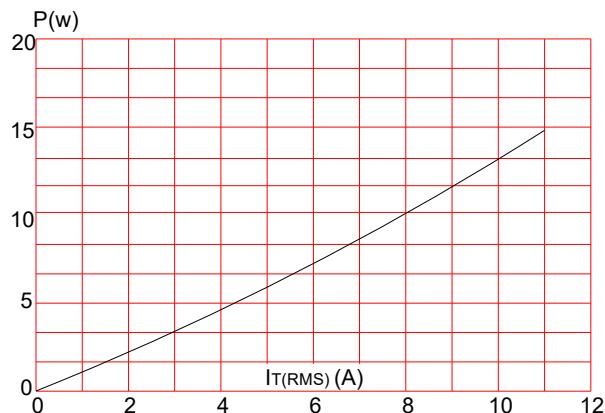
## ORDERING INFORMATION



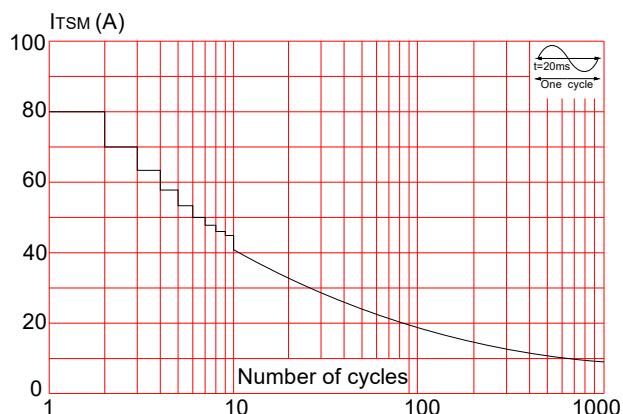
## MARKING



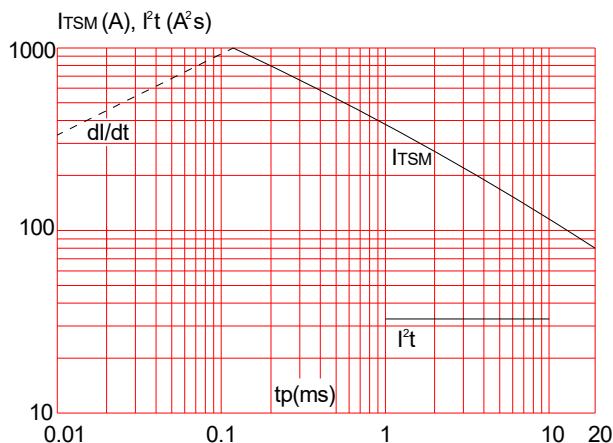
**FIG.1:** Maximum power dissipation versus RMS on-state current



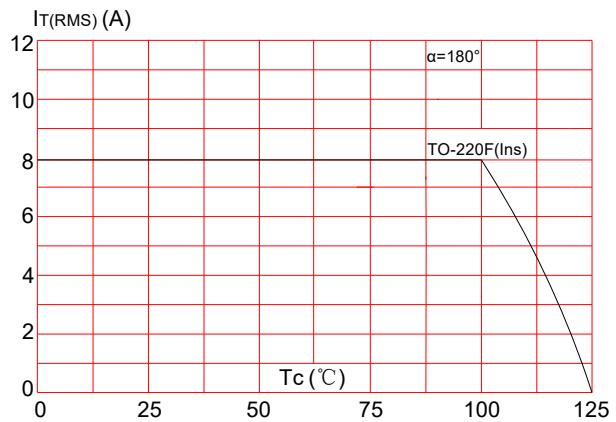
**FIG.3:** Surge peak on-state current versus number of cycles



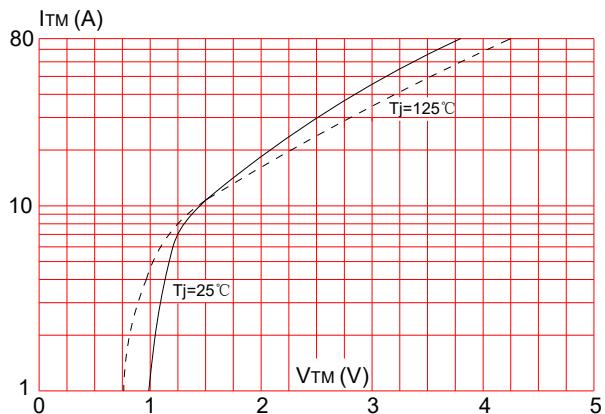
**FIG.5:** Non-repetitive surge peak on-state current for a sinusoidal pulse with width  $t_p < 20\text{ms}$ , and corresponding value of  $I^2t$  ( $dI/dt < 50\text{A}/\mu\text{s}$ )



**FIG.2:** RMS on-state current versus case temperature



**FIG.4:** On-state characteristics (maximum values)



**FIG.6:** Relative variations of gate trigger current, holding current and latching current versus junction temperature

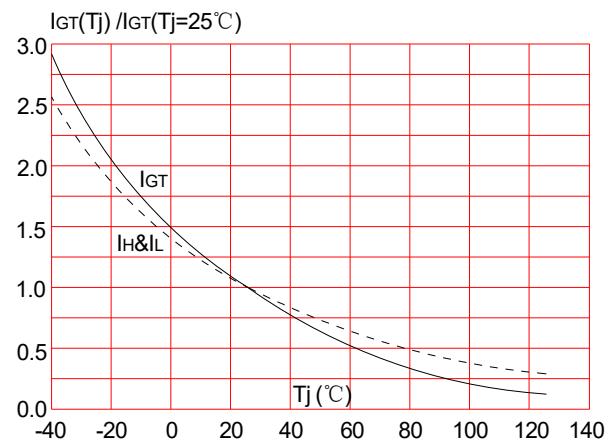
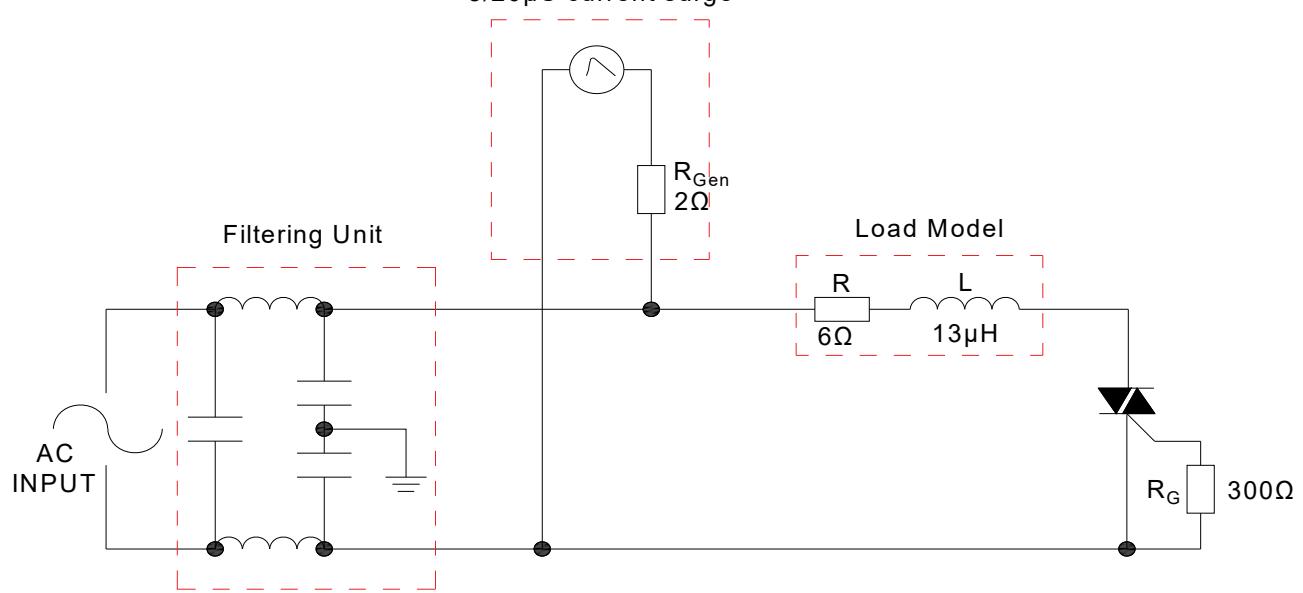


FIG.7: Test circuit for inductive and resistive loads to IEC-61000-4-5 standards.

IEC61000-4-5 Standards  
Surge Generator  
1.2/50 $\mu$ S voltage surge  
8/20 $\mu$ S current surge



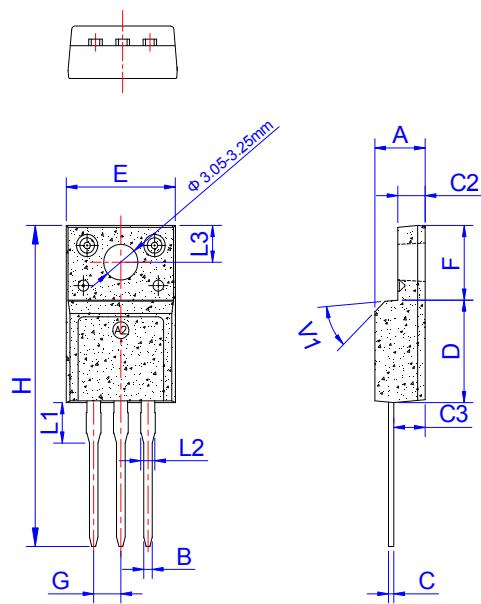
## ORDERING INFORMATION

Order code	Voltage $V_{DRM}/V_{RRM}$ (V)	IGT(mA)	Package	Base qty. (pcs)	Delivery mode
		I - II -III			
ACJM0835-8F	800	35	TO-220F(Ins)	50	Tube

## Document Revision History

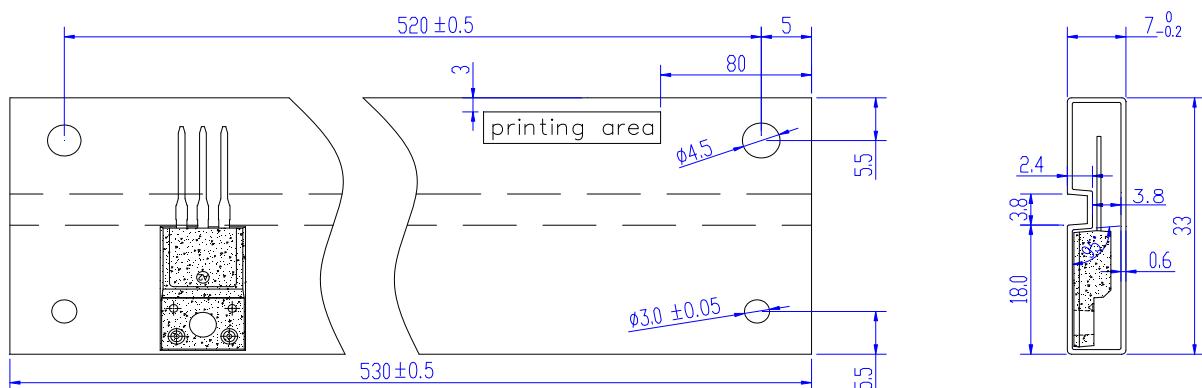
Date	Revision	Changes
Mar 12, 2022	1	Last update

## PACKAGE MECHANICAL DATA



Ref.	Dimensions					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	4.50		4.90	0.177		0.193
B	0.74	0.80	0.83	0.029	0.031	0.033
C	0.47		0.65	0.019		0.026
C2	2.45		2.75	0.096		0.108
C3	2.60		3.00	0.102		0.118
D	8.80		9.30	0.346		0.366
E	9.80		10.4	0.386		0.410
F	6.40		6.80	0.252		0.268
G	2.40		2.70	0.094		0.106
H	28.0		29.8	1.102		1.173
L1		3.63			0.143	
L2	1.14		1.70	0.045		0.067
L3		3.30			0.130	
V1		45°			45°	

## DELIVERY MODE



PACKAGE	OUTLINE	TUBE (PCS)	INNER BOX (PCS)	PER CARTON
TO-220F	TUBE	50	1,000	5,000



Information furnished in this document is believed to be accurate and reliable. However, Jiangsu JieJie Microelectronics Co.,Ltd assumes no responsibility for the consequences of use without consideration for such information nor use beyond it. Information mentioned in this document is subject to change without notice, apart from that when an agreement is signed, Jiangsu JieJie complies with the agreement. Products and information provided in this document have no infringement of patents. Jiangsu JieJie assumes no responsibility for any infringement of other rights of third parties which may result from the use of such products and information. This document supersedes and replaces all information previously supplied.

is a registered trademark of Jiangsu JieJie Microelectronics Co.,Ltd.

Copyright ©2022 Jiangsu JieJie Microelectronics Co.,Ltd. Printed All rights reserved.